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RFVA2017

ANALOG CONTROLLED VARIABLE GAIN AMPLIFIER

Package: MCM, 7mm x 7mm



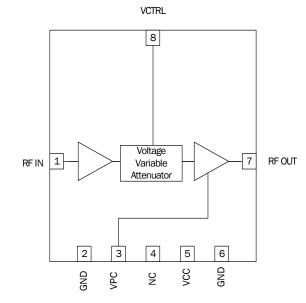


Features

- 2260MHz to 2440MHz Operation
- Gain = 24dB Typical
- Gain Adjustment Range >19dB
- ACPR = -66dBc Typ. at +12dBm P_{OUT} (Dual Carrier WCDMA)
- Small 7mm x 7mm, Multi-Chip Module

Applications

- Cellular, 3G and 4G Infrastructure
- WiBro, WiMax, LTE
- Microwave Radio
- High Linearity Power Control



Functional Block Diagram

Product Description

RFMD's RFVA2017 is a fully integrated analog controlled variable gain amplifier featuring exceptional linearity over a greater than 19dB gain control range. This variable gain amplifier is controlled by a single OV to 3.3V positive supply voltage. The RFVA2017 is packaged in a small 7mm x 7mm leadless laminate MCM which contains thermal vias for ultra low thermal resistance. This module is internally matched to 50Ω and is easy to use with no external matching components required.

Ordering Information

-	
RFVA2017SQ	Sample bag with 25 pieces
RFVA2017SR	7" Sample reel with 100 pieces
RFVA2017TR7	7" Reel with 1500 pieces
RFVA2017TR13	13" Reel with 2500 pieces
RFVA2017PCK-410	2260MHz to 2440MHz PCBA with 5-piece sample bag

Optimum Technology Matching® Applied

🗌 GaAs HBT	□ SiGe BiCMOS	🗹 GaAs pHEMT	🗌 GaN HEMT
□_GaAs MESFET	Si BiCMOS	Si CMOS	BIFET HBT
🗹 InGaP HBT	SiGe HBT	🗌 Si BJT	

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Absolute Maximum Ratings

Parameter	Rating	Unit
Max Device Current	770	mA
Max Device Voltage	5.5	V
Max Control Line Voltage	6	V
Max RF Input Power*	25	dBm
Max Junction Temp (T _J)	+150	°C
Max Storage Temp	+150	°C
Thermal Resistance (junction to backside of module)	14.8	°C/W
ESD	Class 1C (1000V min)	
Moisture Sensitivity Level	MSL3	



Caution! ESD sensitive device.

Exceeding any one or a combination of the Absolute Maximum Rating conditions may cause permanent damage to the device. Extended application of Absolute Maximum Rating conditions to the device may reduce device reliability. Specified typical performance or functional operation of the device under Absolute Maximum Rating conditions is not implied.

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RoHS (Restriction of Hazardous Substances): Compliant per EU Directive 2002/95/EC.

*Load condition: $Z_L = 50\Omega$

Doromotor	Specification		11			
Parameter	Min.	Тур.	Max.	Unit	Condition	
Frequency	2260		2440	MHz		
Temperature Range	-40	25	85	°C	Operating Range	
Gain	21	24	27	dB	Min attenuator setting	
Nominal Operating Output Power		12		dBm	Operating power for ACPR rating	
Output IP3	40	44		dBm	In high gain setting	
P1dB	25	29		dBm	In high gain setting	
ACPR	-60	-66		dBc	Dual carrier WCDMA, 7.5dB CF at nominal operating power; over full attenuation range	
Gain Flatness		0.2	0.4	dB	Over 50MHz BW	
Gain Adjustment Range	19	22		dB		
Control Voltage Range	0		3.3	V		
Noise Figure		4.3	5.3	dB	Min attenuator setting	
Impedance		50		Ω		
Input Return Loss	14	22		dB	Over attenuation range	
Output Return Loss	14	23		dB	Over attenuation range	
Supply Voltage	4.75	5.0	5.25	V		
Supply Current	300	460	600	mA	Max current at -40°C	
Supply Current (VPC = OV)	120	126	140	mA	Output amplifier shutdown total current	



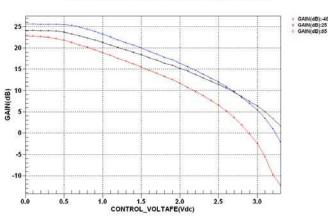
IIP3(dBm):-40 IIP3(dBm):25 IIP3(dBm):85

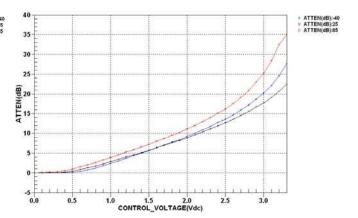


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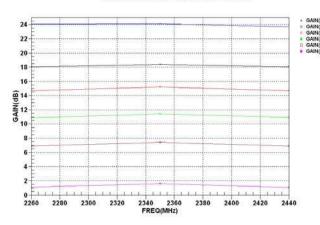
ATTENUATION VS. CONTROL VOLTAGE VS. TEMPERATURE @ 2350 MHz

GAIN VS. CONTROL VOLTAGE VS. TEMPERATURE @ 2350 MHz

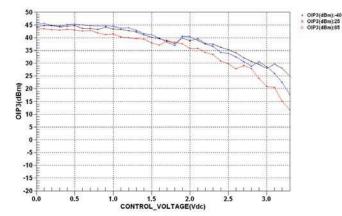




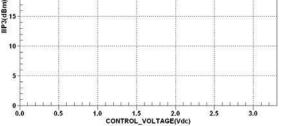
GAIN VS. FREQUENCY VS.CONTROL VOLTAGE



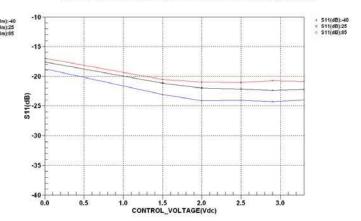
OUTPUT IP3 VS. CONTROL VOLTAGE VS. TEMPERATURE @ 2350 MHz



INPUT IP3 VS. CONTROL VOLTAGE VS. TEMPERATURE @ 2350 MHz







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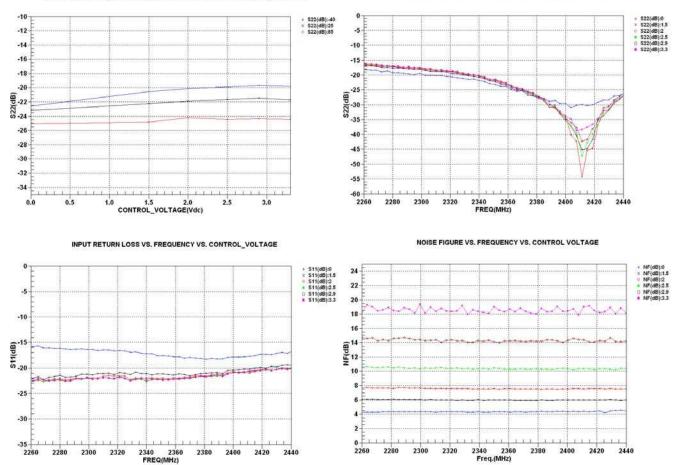
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OUTPUT RETURN LOSS VS. FREQUENCY VS. CONTROL VOLTAGE

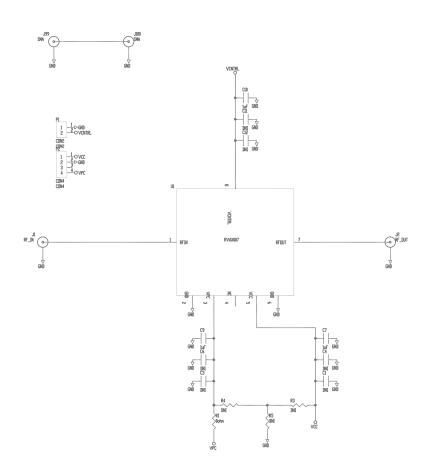
OUTPUT RETURN LOSS VS. CONTROL VOLTAGE VS. TEMPERATURE @ 2350 MHz







Evaluation Board Schematic



Evaluation Board Bill of Materials (BOM)

Description	Reference Designator	Manufacturer	Manufacturer's P/N
EVALUATION BOARD		DDI	RFVAx007L410(A)
CAP, 1µF, 10%, 10V, X5R, 0402	C7, C9-C10	MURATA ELECTRONICS	GRM155R61A105KE15D
RES, 0Ω , 0402	R1	KAMAYA, INC	RMC1/16SJPTH
CONN, SMA, END LAUNCH, UNIV, HYB MNT, FLT	J1-J2	HEILIND ELECTRONICS	PER MAT-21-1038
CONN, HDR, ST, PLRZD, 4-PIN, 0.100"	P2	ITW PANCON	MPSS100-4-C
CONN, HDR, ST, PLRZD, 2-PIN, 0.100"	P1	ITW PANCON	MPSS100-2-C
DNP	C1, C3-C4, C6, C11-C12, R3-R5		
RFVA2017 MODULE	U1	RFMD	RFVA2017

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Pin Table and Description

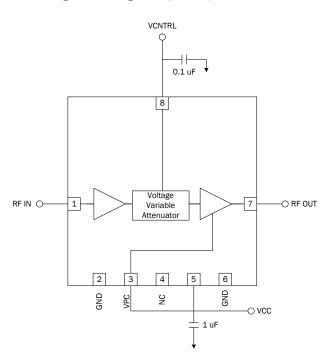
Pin	Function	Description
1	RFIN	RF input pin. Internal DC block.
2	GND	Ground pin.
3	VPC	Power up/down control for 2nd stage amplifier. Apply V_{CC} to power on 2nd stage amplifier. Apply OV to disable 2nd stage amplifier. Do not exceed V_{CC} + 0.5V. Connect to V_{CC} if not needed. Decoupling capacitor may be desired on application board for control line noise.
4	NC	No connection.
5	VCC	Power supply for the module. Recommending $\mbox{1}\mu\mbox{F}$ decoupling cap on the application board.
6	GND	Ground pin.
7	RFOUT	RF output pin. Internal DC block.
8	VCTRL	Gain control voltage; 0V to 3.3V range. Maximum gain at 0V. Recommending 0.1µF decoupling on the applica- tion board.
Center Pad	GND	Center ground pads need to have a good thermal path on the application board. Use solder stencil pattern shown in the document to define solder paste during assembly.





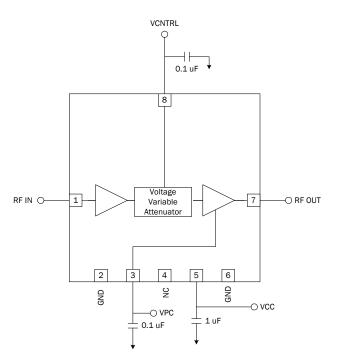
Application Schematic

(Without using final stage amplifier power down control)



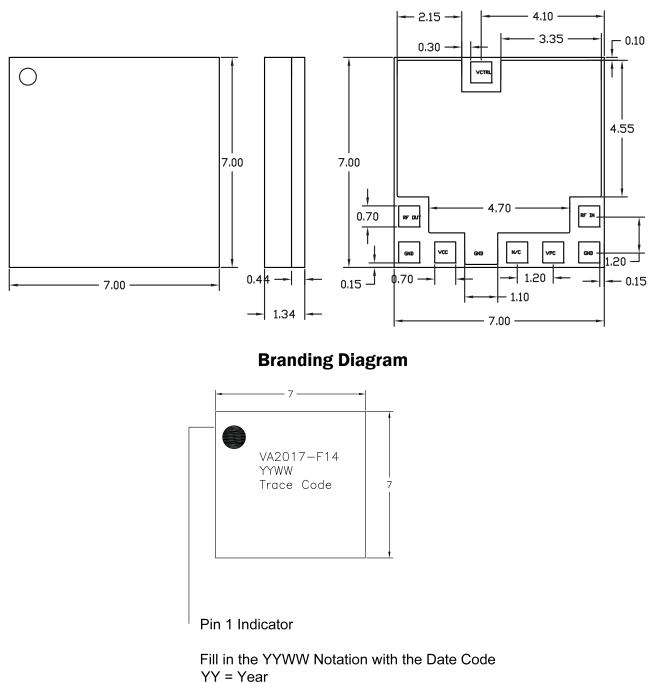
Application Schematic

(Using final stage amplifier power down control)





Package Drawing

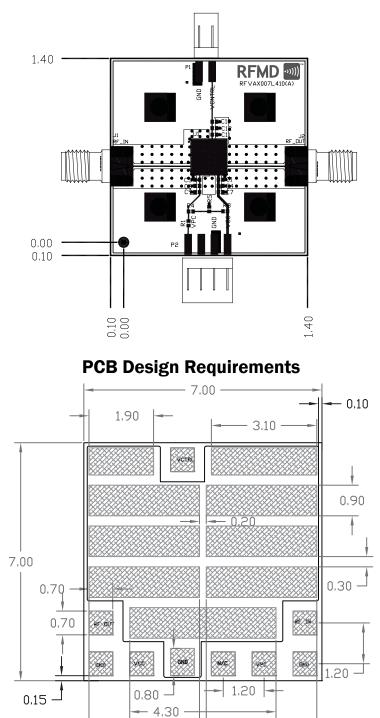


WW = Week

Trace Code to be assigned by SubCon







Evaluation Board Assembly Drawing

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3.25

3.25

 $XX = \pm .05$